




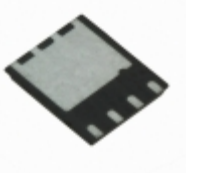




	<h2 style="color: red;">IRFH5302TRPBF</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: IRFH5302TRPBF
	Hersteller / Marke: International Rectifier (Infineon Technologies)
	Teil der Beschreibung: MOSFET N-CH 30V 32A 5X6 PQFN
	Datenblätter:  IRFH5302TRPBF.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 48896 pcs Stock Available.
	Liefern von: Hong Kong
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	IRFH5302TRPBF
Hersteller	International Rectifier (Infineon Technologies)
Beschreibung	MOSFET N-CH 30V 32A 5X6 PQFN
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	48896 pcs Stock
Serie	HEXFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	8-PowerVDFN
Supplier Device-Gehäuse	PQFN (5x6) Single Die
Verlustleistung (max)	3.6W (Ta), 100W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	32A (Ta), 100A (Tc)
Rds On (Max) @ Id, Vgs	2.1 mOhm @ 50A, 10V
VGS (th) (Max) @ Id	2.35V @ 100µA
Gate Charge (Qg) (Max) @ Vgs	76nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	4400pF @ 15V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

IRFH5302TRPBF ist neu im Original, Suche IRFH5302TRPBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFH5302TRPBF International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IRFH5302TRPBF: Info@Y-IC.com

Sie können auch interessiert sein:

 IRFH5302DTRPBF International Rectifier (Infineon Technologies) MOSFET N-CH 30V 29A 8VQFN	 IRFH5302TR2PBF International Rectifier (Infineon Technologies) MOSFET N-CH 30V 32A 5X6 PQFN	 IRFH5302TRPBF. IR IR PQFN-8L(56)	 IRFH5303TRPBF International Rectifier (Infineon Technologies) MOSFET N-CH 30V 82A 8-PQFN
 IRFH5302PBF IR IRFH5302PBF IR	 IRFH5302DTRPBF. IR IR QFN	 IRFH5302DTR2PBF International Rectifier (Infineon Technologies) MOSFET N-CH 30V 29A 8VQFN	 IRFH5303TRPBF. IR IR QFN

heiße Teile

Mehr

 IRFH5104TRPBF	 IRFH5106TRPBF	 IRFH5110TRPBF.	 IRFH5204TR2PBF	 IRFH5204TRPBF
 IRFH5204TRPBF.	 IRFH5206TRPBF	 IRFH5206TRPBF.	 IRFH5207TRPBF	 IRFH5207TRPBF.
 IRFH5210TRPBF	 IRFH5215TRPBF	 IRFH5220TR2PBF	 IRFH5220TRPBF	 IRFH5250DTRPBF
 IRFH5250PBF	 IRFH5250TRPBF	 IRFH5255TRPBF	 IRFH5300TRPBF	 IRFH5301PBF
 IRFH5301TR2PBF	 IRFH5301TRPBF	 IRFH5302DTR2PBF	 IRFH5302DTRPBF	 IRFH5302PBF
 IRFH5303TR2PBF	 IRFH5303TRPBF	 IRFH5304TR2PBF	 IRFH5304TRPBF	 IRFH5304TRPBF
 IRFH5304TRPBF.	 IRFH5306PBF	 IRFH5306TRPBF	 IRFH5306TRPBF.	 IRFH5406TRPBF
 IRFH6200PBF	 IRFH6200TRPBF	 IRFH7004TRPBF	 IRFH7004TRPBF.	 IRFH7084TRPBF
 IRFH7084TRPBF.	 IRFH7107TRPBF	 IRFH7107TRPBF.	 IRFH7110TRPBF	 IRFH7110TRPBF.
 IRFH7182TRPBF	 IRFH7184ATRPBF	 IRFH7184TRPBF	 IRFH7185TRPBF	 IRFH7190ATRPBF

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